

N-channel 60 V 2.2 mΩ standard level MOSFET in TO-220 4 October 2012 Product data sheet

1. Product profile

1.1 General description

Standard level N-channel MOSFET in a TO-220 package qualified to 175 °C. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for standard level gate drive sources

1.3 Applications

- DC-to-DC converters
- Load switching
- Motor control
- Server power supplies

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	-	60	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	[1]	-	-	120	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	338	W
Tj	junction temperature			-55	-	175	°C
Static chara	acteristics	1					
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 12	[2]	-	1.8	2.2	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 100 °C; Fig. 12; Fig. 13		-	3	3.5	mΩ
Dynamic cl	haracteristics						
Q _{GD}	gate-drain charge	V_{GS} = 10 V; I _D = 75 A; V _{DS} = 30 V;		-	32	45	nC
Q _{G(tot)}	total gate charge	<u>Fig. 14; Fig. 15</u>		-	137	192	nC

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Avalanche ruggedness						
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 120 A; V_{sup} ≤ 60 V; R_{GS} = 50 Ω; Unclamped	-	-	913	mJ

Continuous current limited by package
 Measured 3 mm from package.

Pinning information 2.

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D
2	D	drain	$2 \rightarrow 0$	
3	S	source		G C C C C C C C C C C C C C C C C C C C
mb	D	mounting base; connected to drain		mbb076 S
			TO-220AB (SOT78)	

Ordering information 3.

Table 3. Ordering information									
Type number	Package								
	Name	Description	Version						
PSMN2R0-60PS	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78						

4. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN2R0-60PS	PSMN2R0-60PS

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5. Limiting values

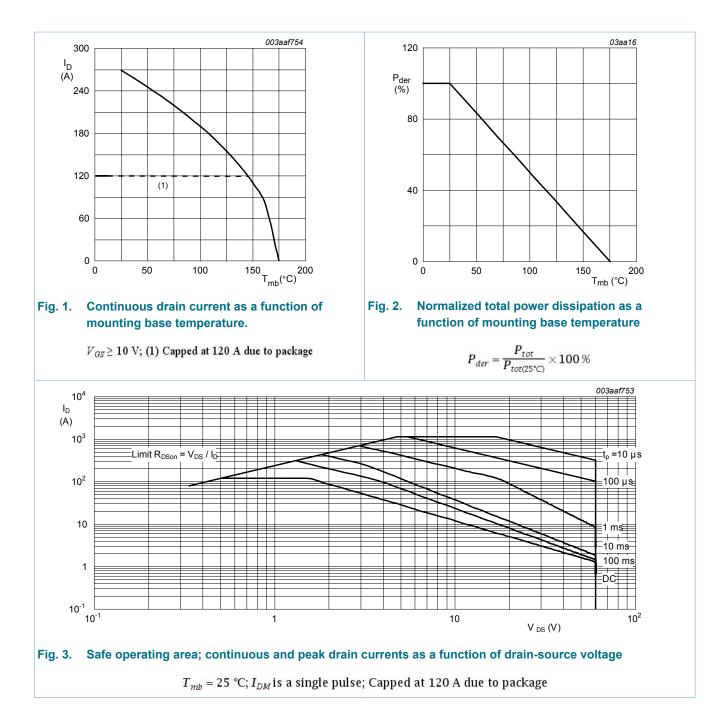
Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	60	V
V _{DGR}	drain-gate voltage	$T_j \ge 25 \text{ °C}; T_j \le 175 \text{ °C}; R_{GS} = 20 \text{ k}\Omega$		-	60	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 1</u>	[1]	-	120	Α
		V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 1</u>	[1]	-	120	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^\circ C$; Fig. 3		-	1135	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	338	W
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-dra	in diode					
I _S	source current	T _{mb} = 25 °C	[1]	-	120	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^\circ C$		-	1135	А
Avalanche	ruggedness					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 120 A; V_{sup} ≤ 60 V; R_{GS} = 50 Ω; Unclamped		-	913	mJ

[1] Continuous current limited by package

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6. Thermal characteristics

Table 6. The	rmal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 4</u>	-	0.22	0.44	K/W

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Symbol	Parameter	Conditions	6		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	Vertical in	free air		-	60	-	K/W
	0.2						03aaf752	
0.	0.1 05 02 single shot				P		$\overline{\delta} = \frac{tp}{T}$	
10 ⁻³ 10 ⁻⁶	10 ⁻⁵	10 ⁻⁴	10 ⁻³	10 ⁻²	10 ⁻¹	t _p (s	⊧ ;) 1	

7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static chara	acteristics						_
V _{(BR)DSS}	drain-source	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C		54	-	-	V
	breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C		60	-	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 175 °C; Fig. 10		1	-	-	V
		I_D = 1 mA; V_{DS} = V_{GS} ; T_j = 25 °C; Fig. 11; Fig. 10		2	3	4	V
		I_D = 1 mA; V_{DS} = V_{GS} ; T_j = -55 °C; Fig. 10		-	-	4.6	V
I _{DSS}	drain leakage current	V _{DS} = 60 V; V _{GS} = 0 V; T _j = 25 °C		-	0.03	10	μA
		V_{DS} = 60 V; V_{GS} = 0 V; T_j = 175 °C		-	-	500	μA
I _{GSS}	gate leakage current	V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C		-	-	100	nA
		V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C		-	-	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 12	[1]	-	1.8	2.2	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 12; Fig. 13		-	4.3	5.1	mΩ

PSMN2R0-60PS

Product data sheet

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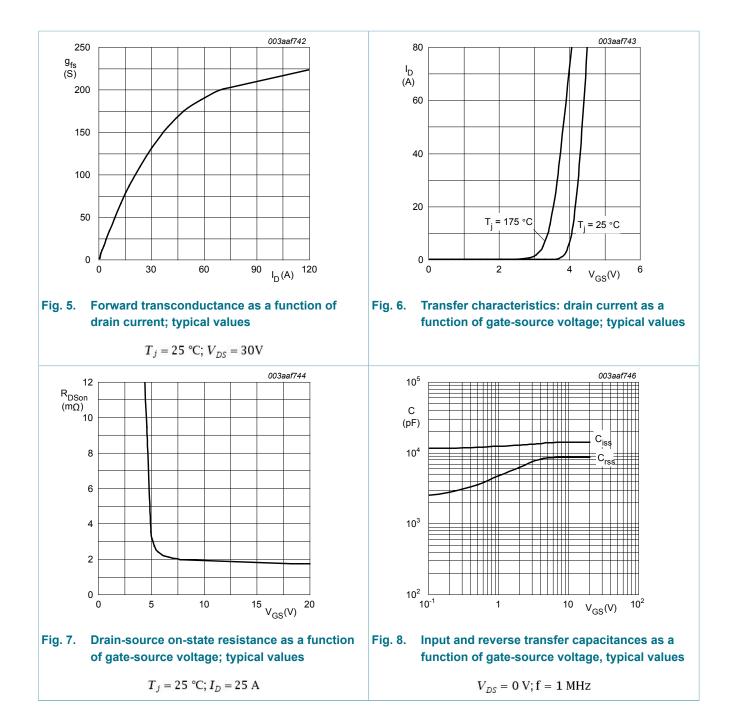
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V _{GS} = 10 V; I _D = 25 A; T _j = 100 °C; Fig. 12; Fig. 13	-	3	3.5	mΩ
R _G	gate resistance	f = 1 MHz	0.45	0.9	1.8	Ω
Dynamic ch	naracteristics	· · · ·				
Q _{G(tot)}	total gate charge	I _D = 75 A; V _{DS} = 30 V; V _{GS} = 10 V; Fig. 14; Fig. 15	-	137	192	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V; Fig. 14; Fig. 15	-	129	181	nC
Q _{GS}	gate-source charge	I_D = 75 A; V_{DS} = 30 V; V_{GS} = 10 V	-	48	68	nC
Q _{GS(th)}	pre-threshold gate- source charge	I _D = 75 A; V _{DS} = 30 V; V _{GS} = 10 V; Fig. 14; Fig. 15	-	29	-	nC
$Q_{GS(th-pl)}$	post-threshold gate- source charge		-	19	-	nC
Q _{GD}	gate-drain charge		-	32	45	nC
$V_{GS(pl)}$	gate-source plateau voltage	V _{DS} = 30 V; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	5.7	-	V
C _{iss}	input capacitance	V _{DS} = 30 V; V _{GS} = 0 V; f = 1 MHz;	-	9997	13500	pF
C _{oss}	output capacitance	$T_j = 25 \text{ °C}; \text{ Fig. 16}$	-	1210	1640	pF
C _{rss}	reverse transfer capacitance		-	594	835	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; R _L = 0.4 Ω; V _{GS} = 10 V;	-	42	63	ns
t _r	rise time	$R_{G(ext)} = 4.7 \ \Omega; I_D = 75 \ A$	-	56	84	ns
t _{d(off)}	turn-off delay time		-	115	173	ns
t _f	fall time		-	49	74	ns
Source-dra	in diode	· · · · · · · · · · · · · · · · · · ·				
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 17</u>	-	0.8	1.2	V
t _{rr}	reverse recovery time	$I_{S} = 25 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V}; \\ \text{V}_{DS} = 30 \text{ V}$	-	57	75	ns
Q _r	recovered charge	I_{S} = 25 A; dI _S /dt = -100 A/µs; V _{GS} = 0 V; V _{DS} = 30 V	-	80	104	nC

[1] Measured 3 mm from package.

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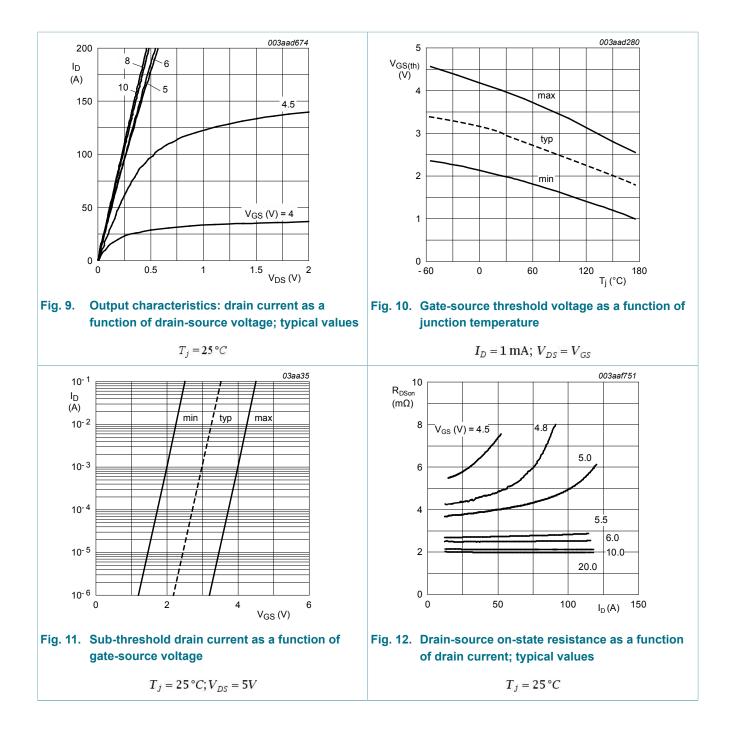
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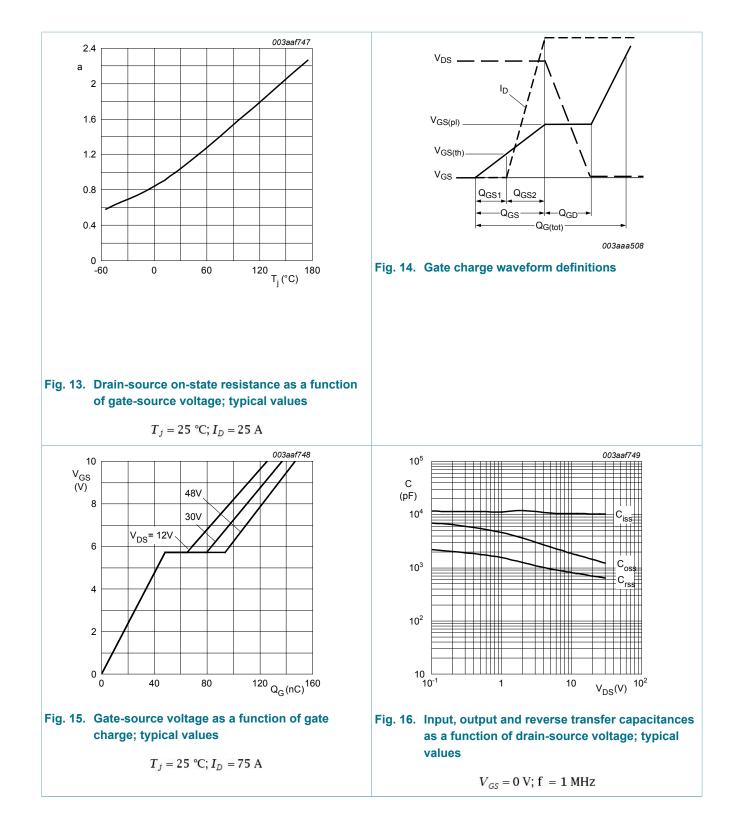
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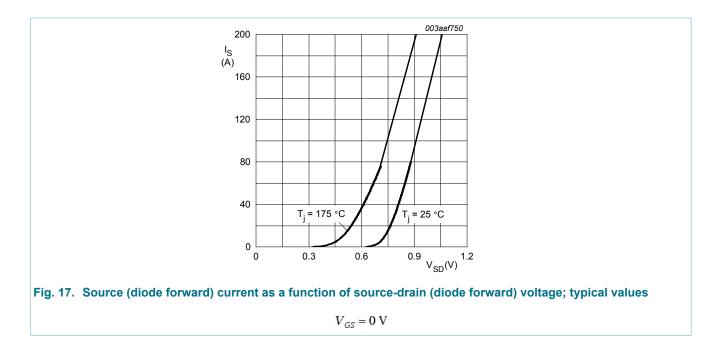
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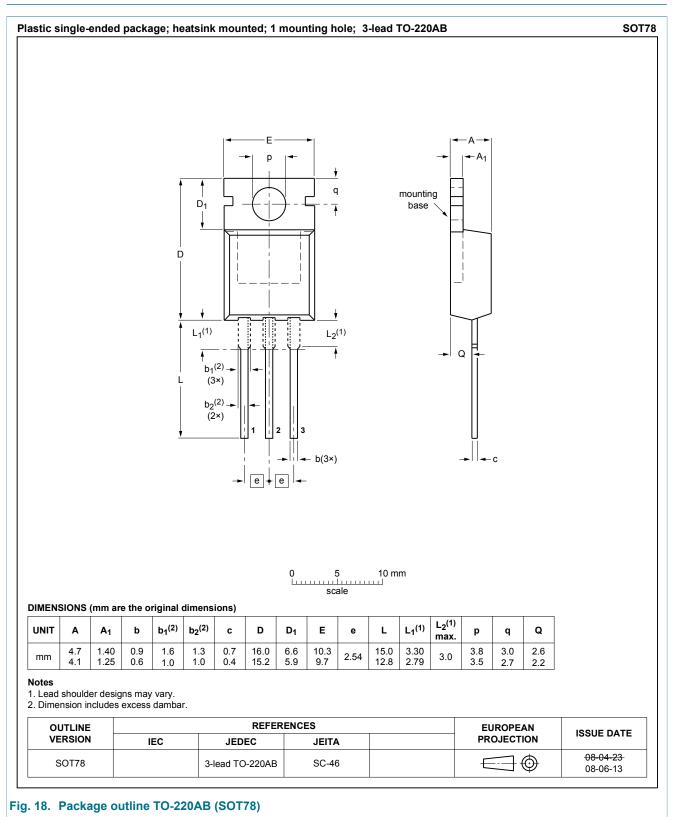
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8. Package outline



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9. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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